Docket No.

209284US99

IN RE APPLICATION OF: Zhiyi YU, et al.

SERIAL NO: 09/842,734

FILED:

April 26, 2001

FOR:

STRUCTURE AND METHOD FOR FABRICATING SEMICONDUCTOR STRUCTURES AND DEVICES

USING BINARY METAL OXIDE LAYERS

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

Transmitted herewith is an amendment in the above-identified application.

- ☐ No additional fee is required
- ☐ Small entity status of this application under 37 C.F.R. §1.9 and §1.27 is claimed.
- Additional documents filed herewith: Request for Extension of Time (ONE MONTH)

The Fee has been calculated as shown below:

CLAIMS	CLAIMS REMAINING		HIGHEST NUMBER PREVIOUSLY PAID	NO. EXTRA CLAIMS		RATE		CALCULATIONS
TOTAL	7	MINUS	54	0	х	\$50	11	\$0.00
INDEPENDENT	1	MINUS	3	0	х	\$200	И	\$0.00
		☐ MULTIPLE DEPENDENT CLAIMS			+	\$360	11	\$0.00
		TOTAL OF ABOVE CALCULATIONS					\$0.00	
- E		☐ Reduction by 50% for filing by Small Entity					\$0.00	
		☐ Recordation of Assignment				\$40	=	\$0.00
*						TOT	AL	\$0.00

- \square A check in the amount of \$0.00 is attached.
- Credit card payment form is attached to cover the fees in the amount of \$120.00
- Please charge any additional Fees for the papers being filed herewith and for which no check or credit card payment is enclosed herewith, or credit any overpayment to deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.
- If these papers are not considered timely filed by the Patent and Trademark Office, then a petition is hereby made under 37 C.F.R. §1.136, and any additional fees required under 37 C.F.R. §1.136 for any necessary extension of time may be charged to Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

Customer Number

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DOCKET NO: 209284US99

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

ZHIYI YU, ET AL. : EXAMINER: XU, SHOUXIANG

SERIAL NO: 09/842,734

FILED: APRIL 26, 2001 : GROUP ART UNIT: 2811

FOR: STRUCTURE AND METHOD FOR FABRICATING SEMICONDUCTOR STRUCTURES AND DEVICES USING BINARY METAL OXIDE LAYERS

AMENDMENT

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated December 23, 2004, please amend the aboveidentified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 4 of this paper.